



100V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D T _C = +25°C	
100V	8.9mΩ @ V _{GS} = 10V	88A	

Description

This new generation N-Channel Enhancement Mode MOSFET is designed to minimize $R_{DS(ON)}$, yet maintain superior switching performance. This device is ideal for use in notebook battery power management and load switch.

Applications

- Motor Control
- DC-DC Converters
- Power Management

Features

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Thermally Efficient Package-Cooler Running Applications
- High Conversion Efficiency
- Low R_{DS(ON)} Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- <1.1mm Package Profile Ideal for Thin Applications (PowerDI[®])
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

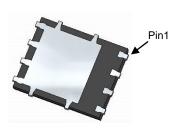
Mechanical Data

- Case: PowerDI5060-8
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminal Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 ⁽³⁾
- Weight: 0.097 grams (Approximate)

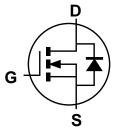
PowerDI5060-8



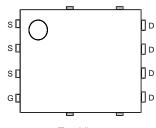
Top View



Bottom View



Internal Schematic



Top View Pin Configuration

Ordering Information (Note 4)

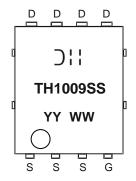
ſ	Part Number	Case	Packaging
	DMTH10H009SPS-13	PowerDI5060-8	2,500 / Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/



Marking Information



] | | = Manufacturer's Marking TH1009SS = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 19 = 2019) WW = Week Code (01 to 53)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V_{DSS}	100	V		
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Drain Current V _{GS} = 10V (Note 6)	Steady State	$T_A = +25$ °C $T_A = +100$ °C	I _D	16 11	А
Continuous Drain Current V _{GS} = 10V (Note 7)	ΙD	88 62	А		
Pulsed Drain Current (10µs Pulse, T _C = +25°C, Package Lin	I _{DM}	350	Α		
Maximum Continuous Body Diode Forward Current	Is	83	Α		
Pulsed Body Diode Current (10µs Pulse, T _C = +25°C, Packa	I _{SM}	350	Α		
Avalanche Current (Note 8), L = 3mH			I _{AS}	11	Α
Avalanche Energy (Note 8), L = 3mH			E _{AS}	181.5	mJ

Thermal Characteristics

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	P_{D}	1.6	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{ heta JA}$	94	°C/W
Total Power Dissipation (Note 6)	$T_A = +25^{\circ}C$	P_{D}	3.2	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{ heta JA}$	47	°C/W
Total Power Dissipation (Note 7)	$T_{C} = +25^{\circ}C$	P_{D}	100	W
Thermal Resistance, Junction to Case (Note 7)		$R_{\theta JC}$	1.5	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +175	°C

Notes:

- 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
- 7. Thermal resistance from junction to soldering point (on the exposed drain pad).
- 8. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BV _{DSS}	100	_	_	V	$V_{GS} = 0V$, $I_D = 1mA$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 80V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	V _{GS(TH)}	2	_	4	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	6.7	8.9	mΩ	$V_{GS} = 10V, I_D = 20A$	
Diode Forward Voltage	V_{SD}	_	0.8	1.2	V	$V_{GS} = 0V, I_{S} = 13A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	C _{iss}	_	2085	_		$V_{DS} = 50V$, $V_{GS} = 0V$ f = 1MHz	
Output Capacitance	Coss	_	609	_	pF		
Reverse Transfer Capacitance	C_{rss}	_	13	_			
Gate Resistance	R_{g}	_	1.7	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge	Q_g	_	30	_	14 -24 - 42 4		
Gate-Source Charge	Q _{gs}	_	9.5	_	nC	$V_{DD} = 50V, I_{D} = 13A,$ $V_{GS} = 10V$	
Gate-Drain Charge	Q_{gd}	_	7.3	_			
Turn-On Delay Time	t _{D(ON)}	_	9.7	_		$V_{DD} = 50V, V_{GS} = 10V,$ $I_{D} = 13A, R_{g} = 6\Omega$	
Turn-On Rise Time	t _R	_	13.7	_	ns		
Turn-Off Delay Time	t _{D(OFF)}	_	25.1	_	115		
Turn-Off Fall Time	t _F	_	17.3	_			
Reverse Recovery Time	t _{RR}		45	_	ns	I_ 12.4 di/dt 100.4/v.o	
Reverse Recovery Charge	Q _{RR}	_	68	_	nC	I _F = 13A, di/dt = 100A/μs	

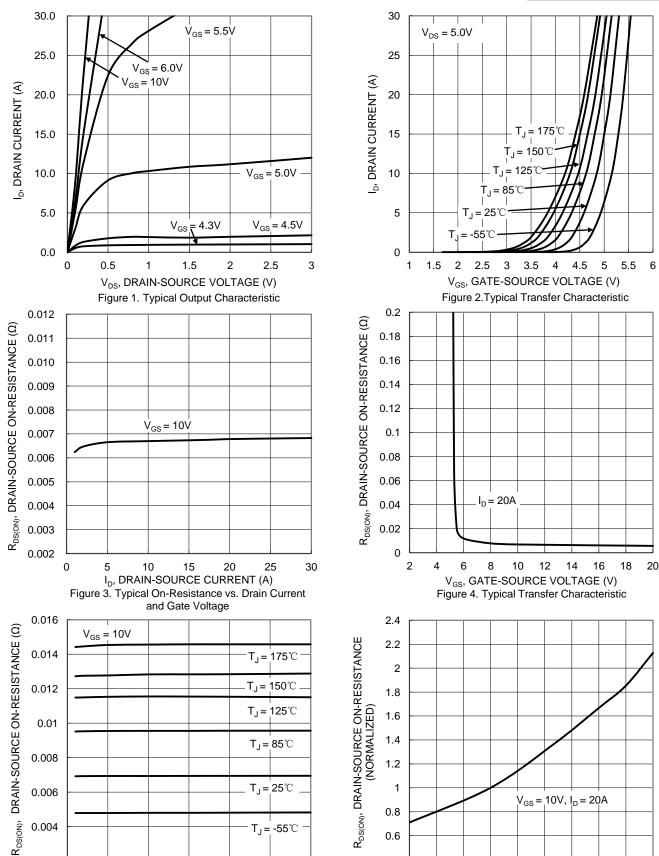
Notes:

Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.



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I_D, DRAIN CURRENT (A) Figure 5. Typical On-Resistance vs. Drain Current and Temperature

15

20

25 50

5

10

0.004

0.002 0 $T_J = -55^{\circ}C$

25

30

8.0

0.6 0.4

-25

75 100 125 150 175





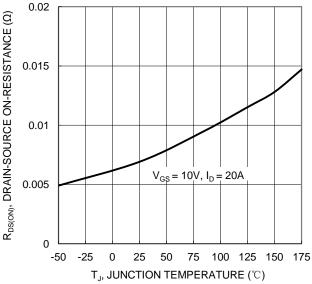
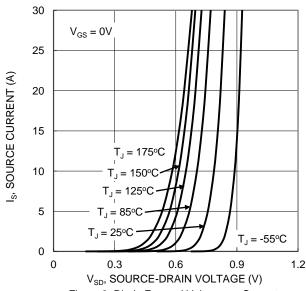


Figure 7. On-Resistance Variation with Temperature



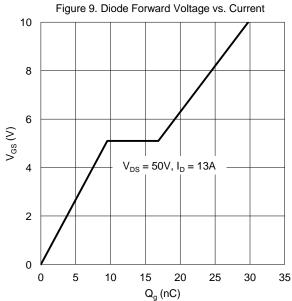


Figure 11. Gate Charge

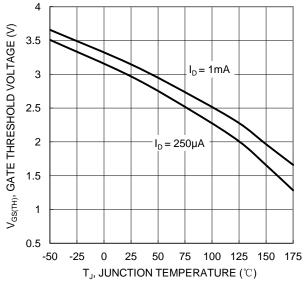


Figure 8. Gate Threshold Variation vs. Junction Temperature

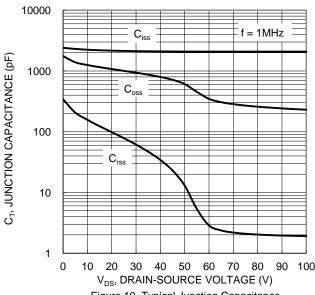


Figure 10. Typical Junction Capacitance

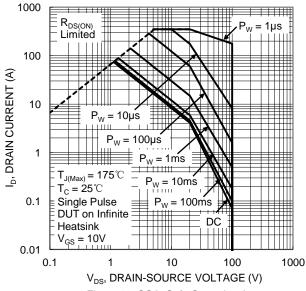


Figure 12. SOA, Safe Operation Area



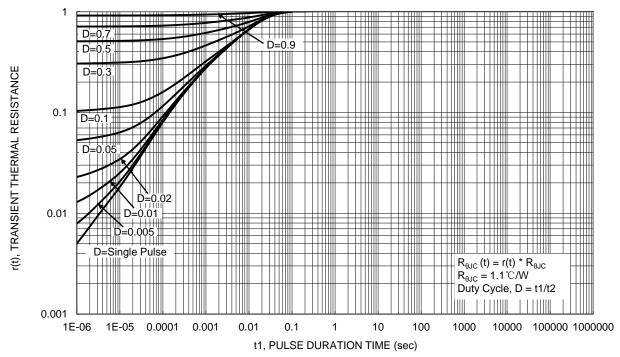


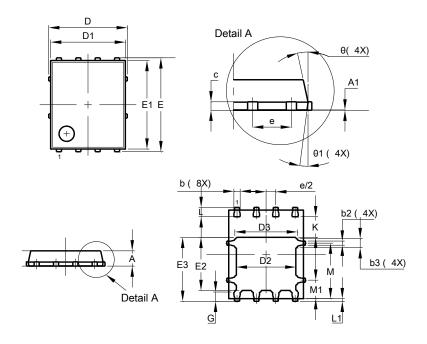
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8

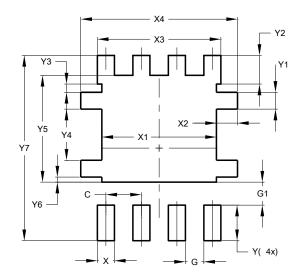


PowerDI5060-8					
Dim	Min	Тур			
Α	0.90	1.10	1.00		
A1	0.00	0.05	-		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D	;	5.15 BSC	;		
D1	4.70	5.10	4.90		
D2	3.70				
D3	3.90 4.30 4.1				
Е		6.15 BSC	;		
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99 4.39 4		4.19		
е	1.27 BSC				
G	0.51 0.71 (0.61		
K	0.51	-	-		
L	0.51 0.71 0.		0.61		
L1	0.100 0.200 0.1		0.175		
М	3.235	235 4.035 3.6			
M1			1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8



Dimensions	Value (in mm)			
С	1.270			
G	0.660			
G1	0.820			
X	0.610			
X1	4.100			
X2	0.755			
Х3	4.420			
X4	5.610			
Y	1.270			
Y1	0.600			
Y2	1.020			
Y3	0.295			
Y4	1.825			
Y5	3.810			
Y6	0.180			
Y7	6.610			



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